NSN 5961-01-450-4308

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-450-4308 **Inclosure Material:** Metal **Overall Length:** 1.000 inches Overall Diameter: 0.375 inches **End Application:** Control-inter e/i fscm 26401 **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Quality assurance level tx and burn in and hermetically sealed case and reverse polarity **Overall Width Across Flats:** 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 13.7 breakdown voltage, dc **Current Rating Per Characteristic:** 3750.00 milliamperes source cutoff current horsepower metric **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector preset **Test Data Document:** 81349-mil-s-19500/358 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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